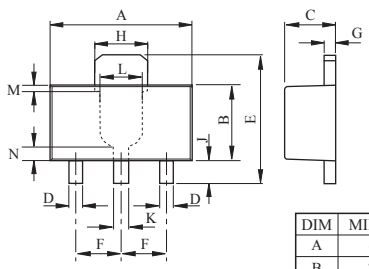
HIGH CURRENT APPLICATION.



DIM	MILLIMETERS
A	4.70 MAX
B	2.50±0.20
C	1.70 MAX
D	0.45+0.15/-0.10
E	4.25 MAX
F	1.50±0.10
G	0.40 TYP
H	1.75 MAX
J	0.75 MIN
K	0.5+0.10/-0.05
L	1.40 ± 0.10
M	0.19 ± 0.10
N	0.47 ± 0.10

1. BASE
2. COLLECTOR (HEAT SINK)
3. EMITTER

SOT-89

FEATURES

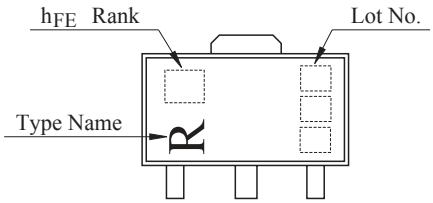
- 1W (Mounted on Ceramic Substrate).
- Small Flat Package.
- Complementary to KTC4376.
- Suffix **U** : Qualified to AEC-Q101.
  ex) KTA1664-Y-RTF/P**U**

MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-35	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-800	mA
Base Current	I_B	-160	mA
Collector Power Dissipation	P_C	500	mW
	P_C*	1	W
Junction Temperature	T_j	150	℃
Storage Temperature Range	T_{stg}	-55 ~ 150	℃

P_C* : KTA1664 mounted on ceramic substrate (250mm²x0.8t)

Marking

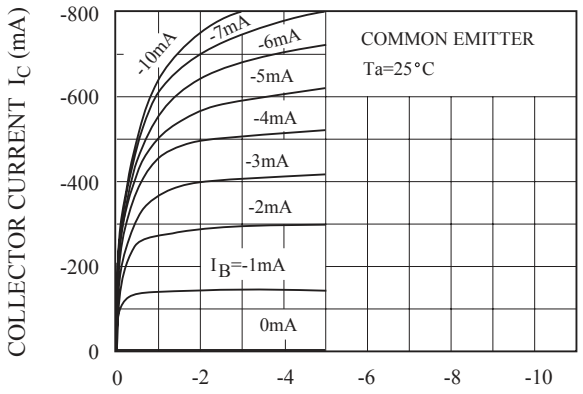


ELECTRICAL CHARACTERISTICS (Ta=25℃)

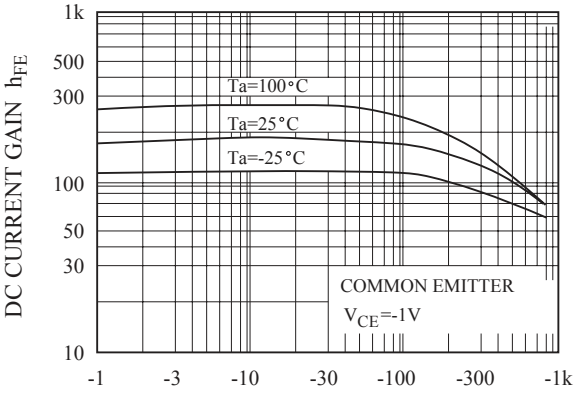
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	V_{CB}=-35V, I_E=0	-	-	-100	nA
Emitter Cut-off Current	I_{EBO}	V_{EB}=-5V, I_C=0	-	-	-100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=-10mA, I_B=0	-30	-	-	V
DC Current Gain	h_{FE}(1) (Note)	V_{CE}=-1V, I_C=-100mA	100	-	320	
	h_{FE}(2)	V_{CE}=-1V, I_C=-700mA	35	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=-500mA, I_B=-20mA	-	-	-0.7	V
Base-Emitter Voltage	V_{BE}	V_{CE}=-1V, I_C=-10mA	-0.5	-	-0.8	V
Transition Frequency	f_T	V_{CE}=-5V, I_C=-10mA	-	120	-	MHz
Collector Output Capacitance	C_{ob}	V_{CB}=-10V, I_E=0, f=1MHz	-	19	-	pF

Note : h_{FE} Classification O:100 ~ 200, Y:160 ~ 320

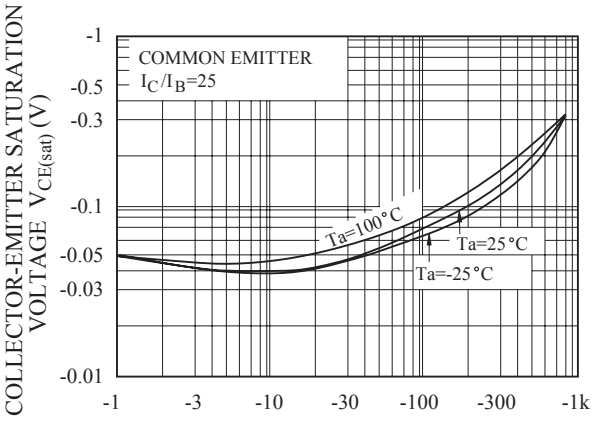
I_C - V_{CE}



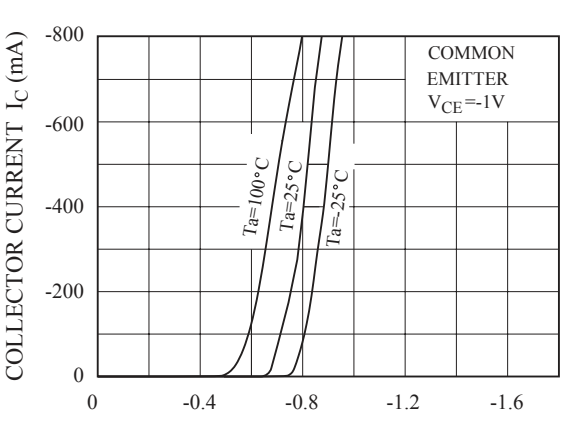
h_{FE} - I_C



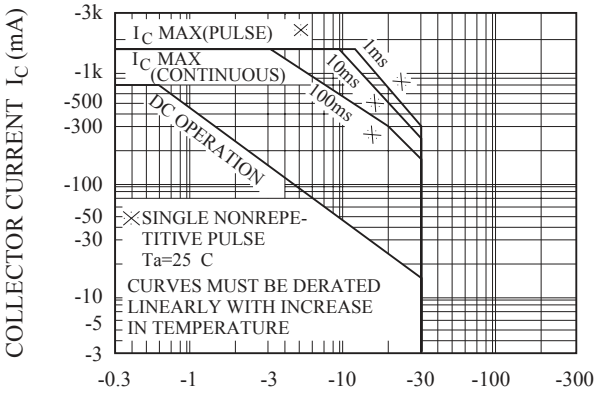
$V_{CE(sat)}$ - I_C



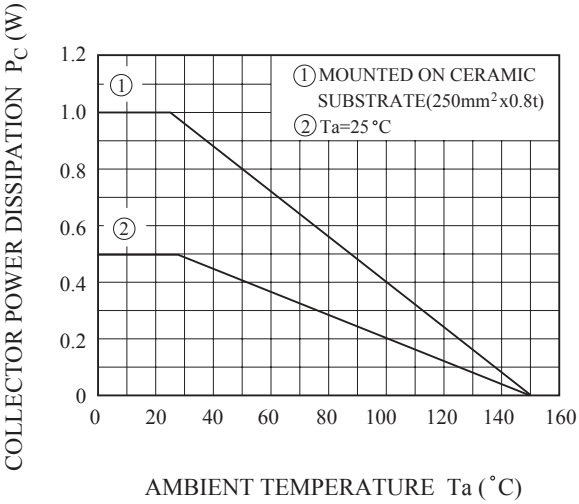
I_C - V_{BE}



SAFE OPERATING AREA



Pc - Ta



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2. When you intend to use these products with equipment or device which require an extremely high of reliability and special applications (such as automobile, air travel aerospace, transportation equipment, life support, system and safety devices) in which special quality and reliability and the failure or malfunction of products may directly jeopardize or harm the human body or damage to property and any application other than the standard application intended, please be sure to consult with our sales representative in advance.

3. On designing your application, please use product within the ranges guaranteed by KEC for maximum rating, operating supply voltage range, heat radiation characteristics and other characteristics. User shall be responsible for failure or damage when used beyond the guaranteed ranges.

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